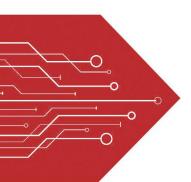
# MSKSEMI















**ESD** 

TVS

**TSS** 

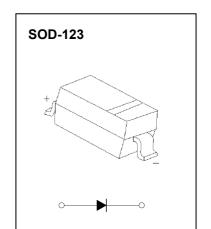
MOV

**GDT** 

**PLED** 

# Broduct data sheet

Compiance



#### **FEATURES**

For use in low voltage, high frequency inverters Free wheeling, and polarity protection applications.

# Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25℃

Parameter	Symbol	XBS104S14	Unit
Non-Repetitive Peak Reverse Voltage	$V_{RM}$	40	V
Peak Repetitive Peak Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	40	V
RMS Reverse Voltage	$V_{R(RMS)}$	28	V
Average Rectified Output Current	lo	1	Α
Peak Forward Surge Current @t=8.3ms	I <sub>FSM</sub>	9	Α
Repetitive Peak Forward Current	I <sub>FRM</sub>	1.5	Α
Power Dissipation	Pd	500	mW
Thermal Resistance Junction to Ambient	R <sub>0JA</sub>	250	°C/W
Storage Temperature	T <sub>STG</sub>	-55~+150	$^{\circ}\mathbb{C}$

#### ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

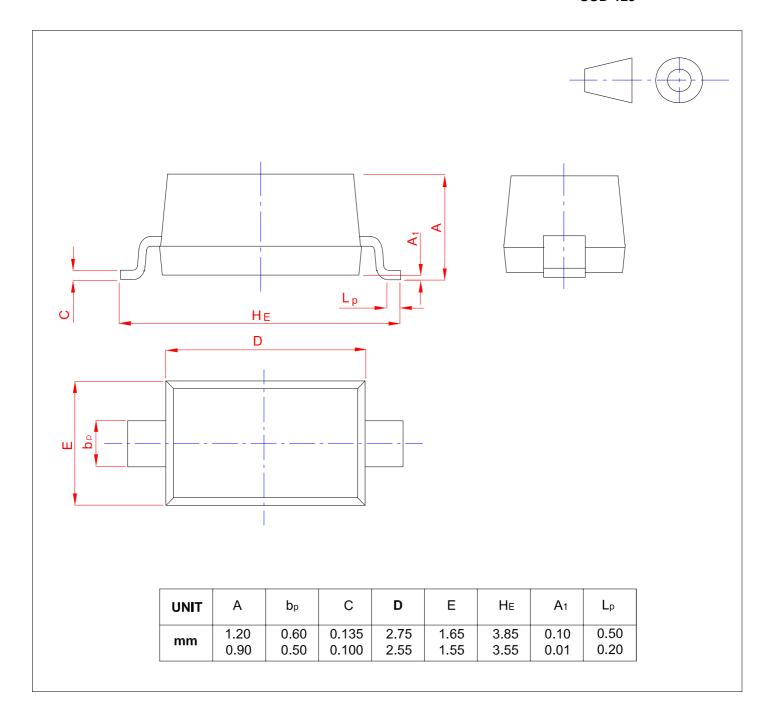
Parameter	Symbol	Test conditions	Min	Max	Unit
Reverse breakdown voltage	V <sub>(BR)</sub>	I <sub>R</sub> = 1mA	40		V
Reverse voltage leakage current	I <sub>R</sub>	V <sub>R</sub> =40V		1	mA
Forward voltage	V <sub>F</sub>	<sub>F</sub> =1A I <sub>F</sub> =3A		0.6 0.9	V
Diode capacitance	$C_D$	V <sub>R</sub> =4V, f=1MHz		120	pF



# **PACKAGE OUTLINE**

#### Plastic surface mounted package; 2 leads

**SOD-123** 











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